

IXFH50N60X

Request a Quote

IXFH50N60X Information

www.heleandr.com	Part Number	IXFH50N60X	
	Manufacturer	IXYS	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	
	Description	MOSFET N-CH 600V 50A TO247	
	Package	TO-247-3	
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



IXFH50N60X Specifications

Manufacturer Part Number	IXFH50N60X
Manufacturer	IXYS
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	ТО-247-3
Series	HiPerFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	600V
Current - Continuous Drain (Id) @ 25°C	50A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4.5V @ 4mA
Gate Charge (Qg) (Max) @ Vgs	116nC @ 10V
Input Capacitance (Ciss) (Max) @ Vds	4660pF @ 25V
Vgs (Max)	±30V
FET Feature	-
Power Dissipation (Max)	660W (Tc)
Rds On (Max) @ Id, Vgs	73 mOhm @ 25A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-247
Package / Case	ТО-247-3
	Report errors?

IXFH50N60X Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

IXFH50N60X Payment Methods



IXFH50N60X Shipping Methods



If you have any question about IXFH50N60X, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com